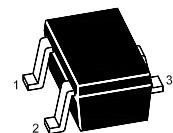


BC846W...BC850W

NPN Silicon Epitaxial Planar Transistor

for general purpose and switching applications



1.Base 2.Emitter 3.Collector
SOT-323 Plastic Package

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	80	V
		50	
		30	
		30	
		50	
Collector Emitter Voltage	V_{CEO}	65	V
		45	
		30	
		30	
		45	
Emitter Base Voltage	V_{EBO}	6	V
		6	
		5	
		5	
		5	
Collector Current	I_C	100	mA
Peak Collector Current	I_{CM}	200	mA
Total Power Dissipation	P_{tot}	200	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	- 55 to + 150	°C

BC846W...BC850W

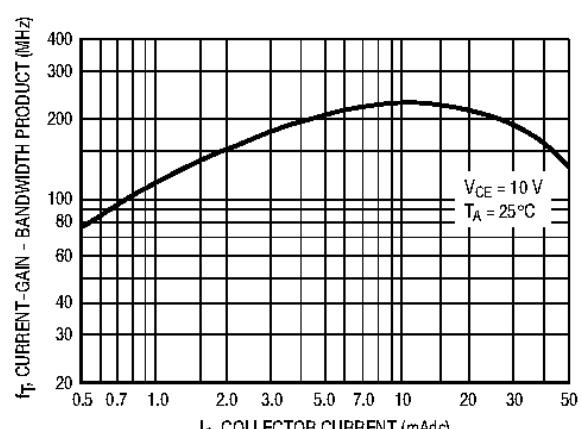
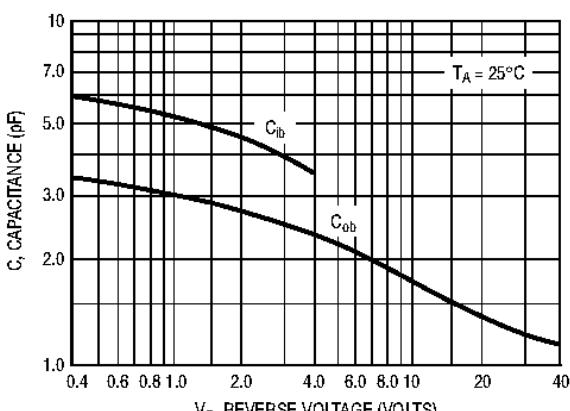
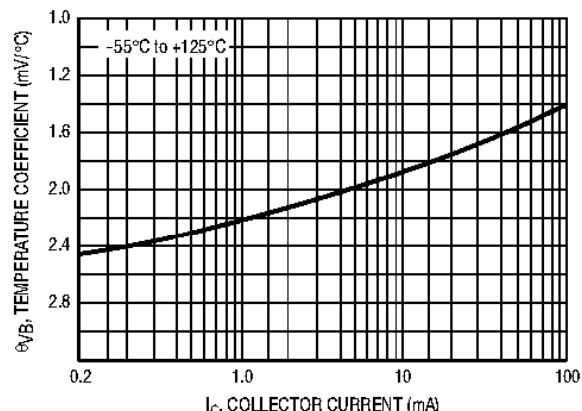
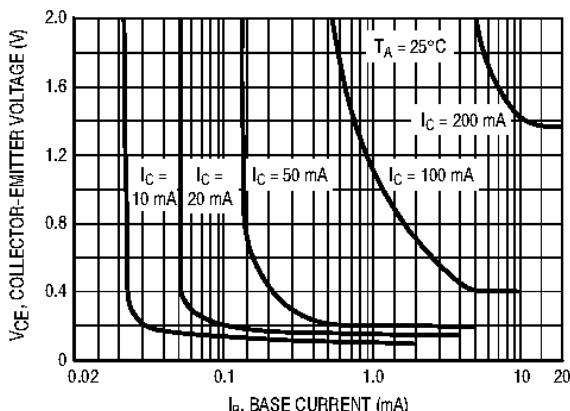
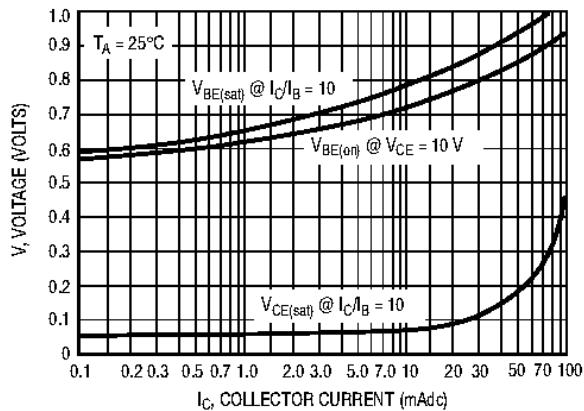
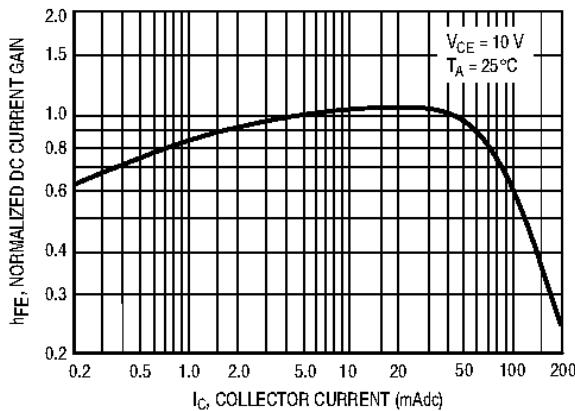
Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
DC Current Gain at $V_{CE} = 5 \text{ V}$, $I_C = 2 \text{ mA}$	h_{FE}	110	220	-
BC846AW~BC850AW		200	450	-
BC846BW~BC850BW		420	800	-
BC846CW~BC850CW				
Collector Base Voltage at $I_C = 10 \mu\text{A}$	V_{CBO}	80	-	
BC846W		50	-	
BC847W		30	-	
BC848W		30	-	
BC849W		50	-	
BC850W				
Collector Emitter Voltage at $I_C = 10 \text{ mA}$	V_{CEO}	65	-	
BC846W		45	-	
BC847W		30	-	
BC848W		30	-	
BC849W		45	-	
BC850W				
Emitter Base Voltage at $I_E = 1 \mu\text{A}$	V_{EBO}	6	-	
BC846W		6	-	
BC847W		5	-	
BC848W		5	-	
BC849W		5	-	
BC850W				
Collector Base Cutoff Current at $V_{CB} = 30 \text{ V}$	I_{CBO}	-	15	nA
Emitter Base Cutoff Current at $V_{EB} = 5 \text{ V}$	I_{EBO}	-	100	nA
Collector Emitter Saturation Voltage at $I_C = 10 \text{ mA}$, $I_B = 0.5 \text{ mA}$ $I_C = 100 \text{ mA}$, $I_B = 5 \text{ mA}$	$V_{CE(\text{sat})}$	-	0.25 0.6	V
Base Emitter Voltage at $V_{CE} = 5 \text{ V}$, $I_C = 2 \text{ mA}$ $V_{CE} = 5 \text{ V}$, $I_C = 10 \text{ mA}$	V_{BE}	0.58 -	0.7 0.77	V
Transition Frequency at $V_{CE} = 5 \text{ V}$, $I_C = 10 \text{ mA}$, $f = 100 \text{ MHz}$	f_T	100	-	MHz
Collector Output Capacitance at $V_{CB} = 10 \text{ V}$, $I_E = 0$, $f = 1 \text{ MHz}$	C_{ob}	-	4.5	pF

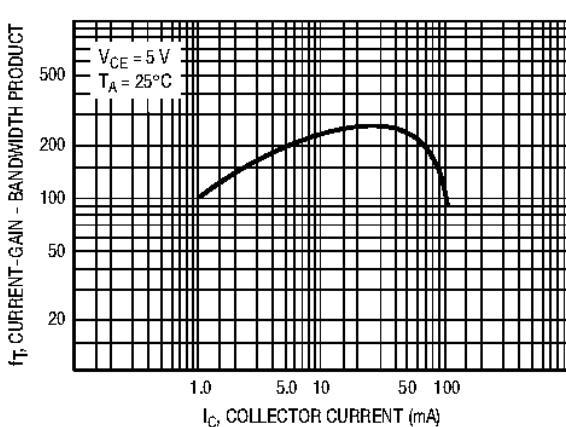
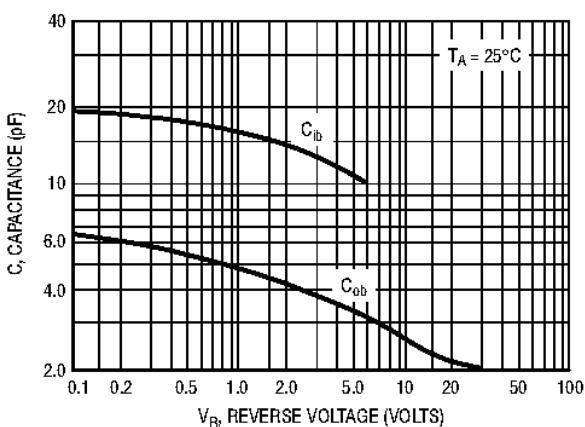
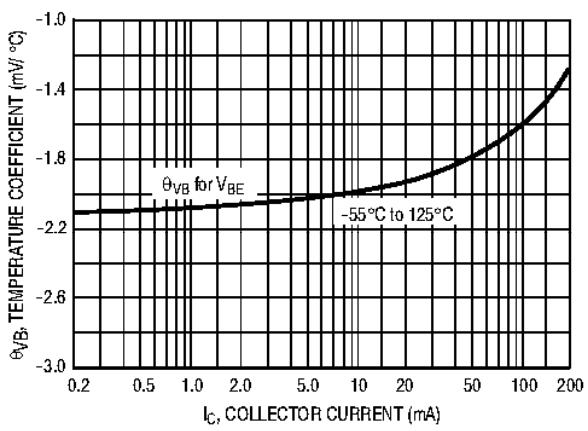
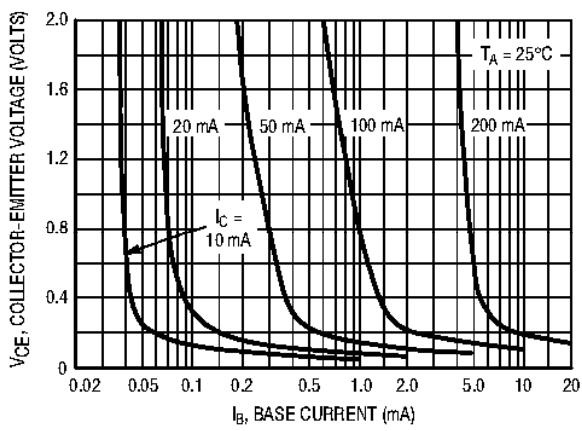
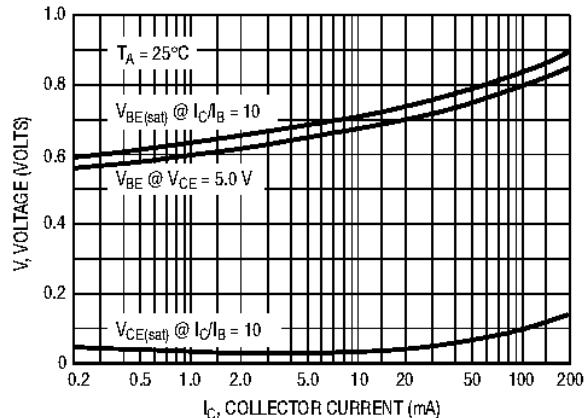
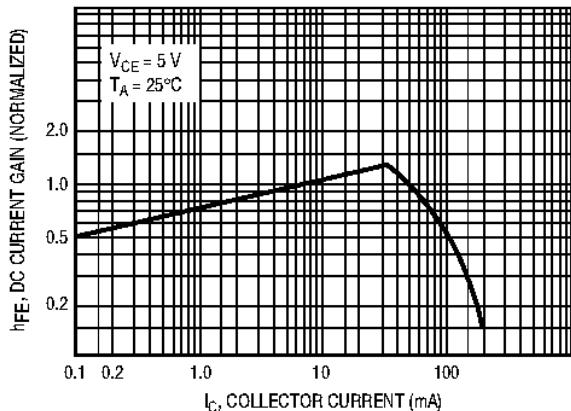
DEVICE MARKING

BC846AW=1A;BC846BW=1B;BC846CW=1C
BC847AW=1E;BC847BW=1F;BC847CW=1G
BC848AW=1J;BC848BW=1K;BC848CW=1L
BC849AW=1E;BC849BW=1F;BC849CW=1G
BC850AW=1E;BC850BW=1F;BC850CW=1G

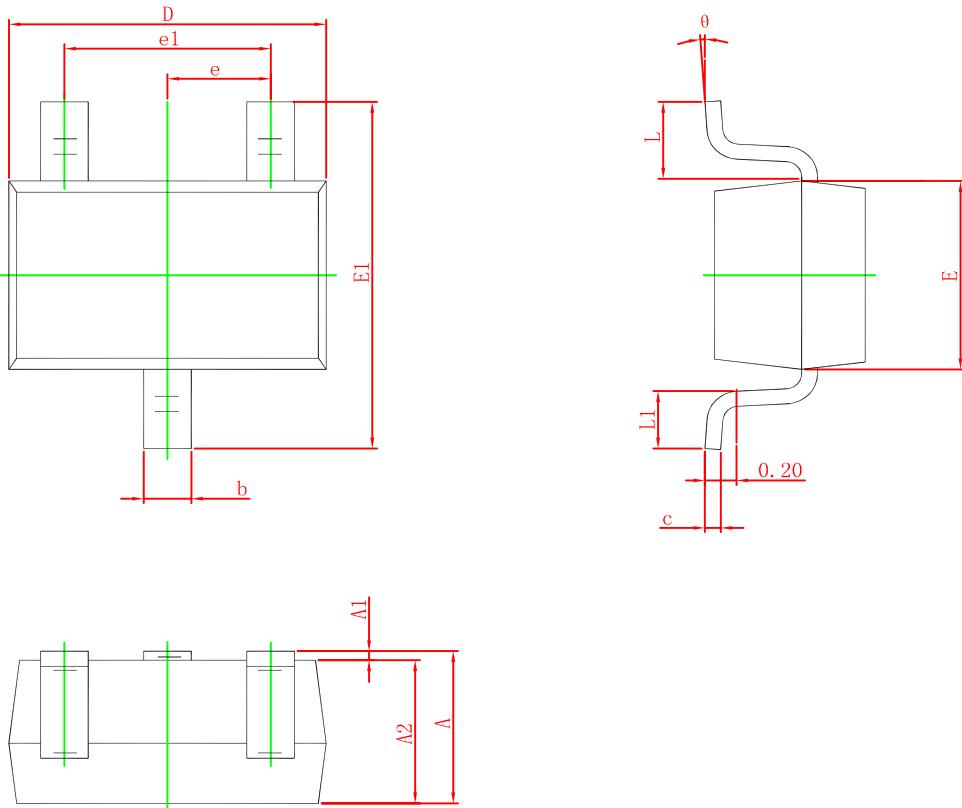
BC846W...BC850W



BC846W...BC850W



SOT-323 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.650 TYP.		0.026 TYP.	
e1	1.200	1.400	0.047	0.055
L	0.525 REF.		0.021 REF.	
L1	0.260	0.460	0.010	0.018
theta	0°	8°	0°	8°

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